

# 128MB - 16Mx72 SDRAM, UNBUFFERED

## FEATURES

- PC100 and PC133 compatible
- Burst Mode Operation
- Auto and Self Refresh capability
- LVTTTL compatible inputs and outputs
- Serial Presence Detect with EEPROM
- Fully synchronous: All signals are registered on the positive edge of the system clock
- Programmable Burst Lengths: 1, 2, 4, 8 or Full Page
- 3.3V  $\pm$  0.3V Power Supply
- 144 Pin SO-DIMM JEDEC
  - Package height options:  
JD1: 31.75 (1.25")

## DESCRIPTION

The W3DG7216V is a 16Mx72 synchronous DRAM module which consists of nine 16Meg x 8 SDRAM components in TSOP II package, and one 2Kb EEPROM in an 8 pin TSSOP package for Serial Presence Detect which are mounted on a 144 pin SO-DIMM multilayer FR4 Substrate.

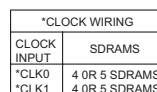
\* This product is under development, is not qualified or characterized and is subject to change without notice.

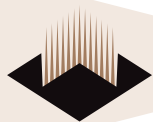
## PIN CONFIGURATIONS (FRONT SIDE/BACK SIDE)

| PINOUT |       |     |       |     |       |     |      |     |       |     |       |
|--------|-------|-----|-------|-----|-------|-----|------|-----|-------|-----|-------|
| PIN    | FRONT | PIN | BACK  | PIN | FRONT | PIN | BACK | PIN | FRONT | PIN | BACK  |
| 1      | Vss   | 2   | Vss   | 49  | DQ13  | 50  | DQ45 | 97  | DQ22  | 98  | DQ54  |
| 3      | DQ0   | 4   | DQ32  | 51  | DQ14  | 52  | DQ46 | 99  | DQ23  | 100 | DQ55  |
| 5      | DQ1   | 6   | DQ33  | 53  | DQ15  | 54  | DQ47 | 101 | Vcc   | 102 | Vcc   |
| 7      | DQ2   | 8   | DQ34  | 55  | Vss   | 56  | Vss  | 103 | A6    | 104 | A7    |
| 9      | DQ3   | 10  | DQ35  | 57  | CB0   | 58  | CB4  | 105 | A8    | 106 | BA0   |
| 11     | Vcc   | 12  | Vcc   | 59  | CB1   | 60  | CB5  | 107 | Vss   | 108 | Vss   |
| 13     | DQ4   | 14  | DQ36  | 61  | CLK0  | 62  | CKE0 | 109 | A9    | 110 | BA1   |
| 15     | DQ5   | 16  | DQ37  | 63  | Vcc   | 64  | Vcc  | 111 | A10   | 112 | A11   |
| 17     | DQ6   | 18  | DQ38  | 65  | RAS#  | 66  | CAS# | 113 | Vcc   | 114 | Vcc   |
| 19     | DQ7   | 20  | DQ39  | 67  | WE#   | 68  | CKE1 | 115 | DQMB2 | 116 | DQMB6 |
| 21     | Vss   | 22  | Vss   | 69  | SO#   | 70  | A12  | 117 | DQMB3 | 118 | DQMB7 |
| 23     | DQMB0 | 24  | DQMB4 | 71  | S1#   | 72  | NC   | 119 | Vss   | 120 | Vss   |
| 25     | DQMB1 | 26  | DQMB5 | 73  | NC    | 74  | NC   | 121 | DQ24  | 122 | DQ56  |
| 27     | Vcc   | 28  | Vcc   | 75  | Vss   | 76  | Vss  | 123 | DQ25  | 124 | DQ57  |
| 29     | A0    | 30  | A3    | 77  | CB2   | 78  | CB6  | 125 | DQ26  | 126 | DQ58  |
| 31     | A1    | 32  | A4    | 79  | CB3   | 80  | CB7  | 127 | DQ27  | 128 | DQ59  |
| 33     | A2    | 34  | A5    | 81  | Vcc   | 82  | Vcc  | 129 | Vcc   | 130 | Vcc   |
| 35     | Vss   | 36  | Vss   | 83  | DQ16  | 84  | DQ48 | 131 | DQ28  | 132 | DQ60  |
| 37     | DQ8   | 38  | DQ40  | 85  | DQ17  | 86  | DQ49 | 133 | DQ29  | 134 | DQ61  |
| 39     | DQ9   | 40  | DQ41  | 87  | DQ18  | 88  | DQ50 | 135 | DQ30  | 136 | DQ62  |
| 41     | DQ10  | 42  | DQ42  | 89  | DQ19  | 90  | DQ51 | 137 | DQ31  | 138 | DQ63  |
| 43     | DQ11  | 44  | DQ43  | 91  | Vss   | 92  | Vss  | 139 | Vss   | 140 | Vss   |
| 45     | Vcc   | 46  | Vcc   | 93  | DQ20  | 94  | DQ52 | 141 | SDA   | 142 | SCL   |
| 47     | DQ12  | 48  | DQ44  | 95  | DQ21  | 96  | DQ53 | 143 | Vcc   | 144 | Vcc   |

## PIN NAMES

|          |                              |
|----------|------------------------------|
| A0 – A12 | Address Input (Multiplexed)  |
| BA0-BA1  | Select Bank                  |
| DQ0-63   | Data Input/Output            |
| CLK0     | Clock Input                  |
| CB0-7    | Check Bit (Data-In/Data-Out) |
| CKE0     | Clock Enable Input           |
| CS0#     | Chip Select Input            |
| RAS#     | Row Address Strobe           |
| CAS#     | Column Address Strobe        |
| WE#      | #Write Enable                |
| DQM0-7   | DQM                          |
| Vcc      | Power Supply (3.3V)          |
| Vss      | Ground                       |
| SDA      | Serial Data I/O              |
| SCL      | Serial Clock                 |
| DNU      | Do Not Use                   |
| NC       | No Connect                   |





### ABSOLUTE MAXIMUM RATINGS

| Parameter                                       | Symbol            | Value      | Units |
|-------------------------------------------------|-------------------|------------|-------|
| Voltage on any pin relative to $V_{SS}$         | $V_{IN}, V_{OUT}$ | -1.0 ~ 4.6 | V     |
| Voltage on $V_{CC}$ supply relative to $V_{SS}$ | $V_{CC}, V_{CCQ}$ | -1.0 ~ 4.6 | V     |
| Storage Temperature                             | $T_{STG}$         | -55 ~ +150 | °C    |
| Power Dissipation                               | $P_D$             | 9          | W     |
| Short Circuit Current                           | $I_{OS}$          | 50         | mA    |

Note: Permanent device damage may occur if "ABSOLUTE MAXIMUM RATINGS" are exceeded.

Functional operation should be restricted to recommended operating condition.

Exposure to higher than recommended voltage for extended periods of time could affect device reliability.

### RECOMMENDED DC OPERATING CONDITIONS

Voltage Referenced to:  $V_{SS} = 0V, 0^{\circ}C \leq T_A \leq +70^{\circ}C$

| Parameter             | Symbol   | Min  | Typ | Max             | Unit    | Note            |
|-----------------------|----------|------|-----|-----------------|---------|-----------------|
| Supply Voltage        | $V_{CC}$ | 3.0  | 3.3 | 3.6             | V       |                 |
| Input High Voltage    | $V_{IH}$ | 2.0  | 3.0 | $V_{CCQ} + 0.3$ | V       | 1               |
| Input Low Voltage     | $V_{IL}$ | -0.3 | —   | 0.8             | V       | 2               |
| Output High Voltage   | $V_{OH}$ | 2.4  | —   | —               | V       | $I_{OH} = -2mA$ |
| Output Low Voltage    | $V_{OL}$ | —    | —   | 0.4             | V       | $I_{OL} = -2mA$ |
| Input Leakage Current | $I_{LI}$ | -10  | —   | 10              | $\mu A$ | 3               |

Note:

1.  $V_{IH} (max) = 5.6V$  AC. The overshoot voltage duration is  $\leq 3ns$ .

2.  $V_{IL} (min) = -2.0V$  AC. The undershoot voltage duration is  $\leq 3ns$ .

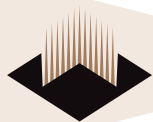
3. Any input  $0V \leq V_{IN} \leq V_{CCQ}$

Input leakage currents include Hi-Z output leakage for all bi-directional buffers with Tri-State outputs.

### CAPACITANCE

$T_A = 25^{\circ}C, f = 1MHz, V_{CC} = 3.3V, V_{REF} = 1.4V \pm 200mV$

| Parameter                                | Symbol     | Max | Unit |
|------------------------------------------|------------|-----|------|
| Input Capacitance (A0-A11)               | $C_{IN1}$  | 40  | pF   |
| Input Capacitance (RAS#,CAS#,WE#)        | $C_{IN2}$  | 40  | pF   |
| Input Capacitance (CKE0)                 | $C_{IN3}$  | 40  | pF   |
| Input Capacitance (CLK0)                 | $C_{IN4}$  | 20  | pF   |
| Input Capacitance (CS0#)                 | $C_{IN5}$  | 40  | pF   |
| Input Capacitance (DQM0-DQM7)            | $C_{IN6}$  | 7   | pF   |
| Input Capacitance (BA0-BA1)              | $C_{IN7}$  | 40  | pF   |
| Data Input/Output Capacitance (DQ0-DQ63) | $C_{OUT}$  | 10  | pF   |
| Data Input/Output Capacitance (CB0-7)    | $C_{OUT1}$ | 10  | pF   |

**OPERATING CURRENT CHARACTERISTICS** $V_{CC} = 3.3V$ ,  $0^{\circ}C \leq T_A \leq +70^{\circ}C$ 

|                                                  |                  |                                                                                                                    | Version |       |      |
|--------------------------------------------------|------------------|--------------------------------------------------------------------------------------------------------------------|---------|-------|------|
| Parameter                                        | Symbol           | Conditions                                                                                                         | 133/100 | Units | Note |
| Operating Current<br>(One bank active)           | I <sub>CC1</sub> | Burst Length = 1<br>$t_{RC} \leq t_{RC(min)}$<br>$I_{OL} = 0mA$                                                    | 1440    | mA    | 1    |
| Precharge Standby Current<br>in Power Down Mode  | I <sub>CC2</sub> | $CKE \leq V_{IL(max)}$ , $t_{CC} = 10ns$                                                                           | 18      | mA    |      |
| Active Standby Current in<br>Non-Power Down Mode | I <sub>CC3</sub> | $CKE \geq V_{IH(min)}$ , $CS \geq V_{IH(min)}$ , $t_{CC} = 10ns$ Input<br>signals are changed one time during 20ns | 450     | mA    |      |
| Operating Current (Burst mode)                   | I <sub>CC4</sub> | $I_O = mA$<br>Page burst<br>4 Banks activated<br>$t_{CCD} = 2CK$                                                   | 1485    | mA    | 1    |
| Refresh Current                                  | I <sub>CC5</sub> | $t_{RC} \geq t_{RC(min)}$                                                                                          | 2970    | mA    | 2    |
| Self Refresh Current                             | I <sub>CC6</sub> | $CKE \leq 0.2V$                                                                                                    | 27      | mA    |      |

## Notes:

1. Measured with outputs open.
2. Refresh period is 64ms.

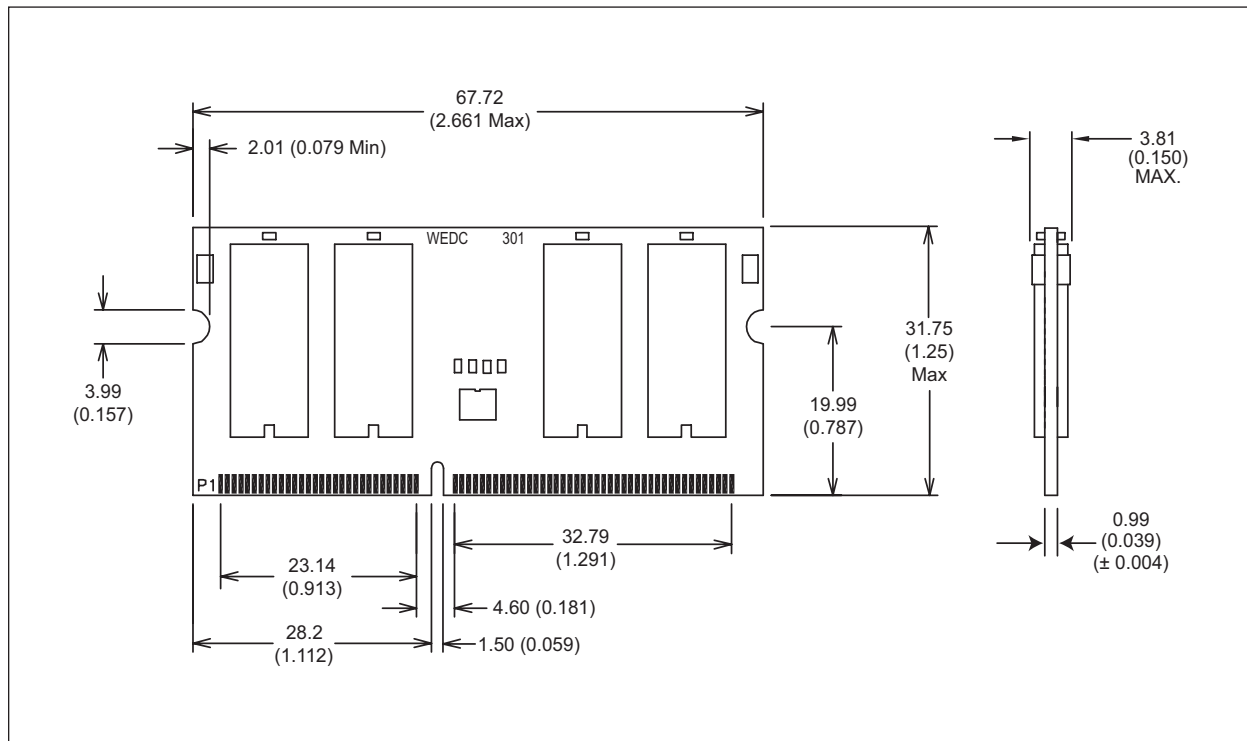


### PACKAGE DIMENSIONS FOR JD1

| Ordering Information | Speed  | CAS Latency | Height*       |
|----------------------|--------|-------------|---------------|
| W3DG7216V10JD1       | 100MHz | CL=2        | 31.75 (1.25") |
| W3DG7216V7JD1        | 133MHz | CL=2        | 31.75 (1.25") |
| W3DG7216V75JD1       | 133MHz | CL=3        | 31.75 (1.25") |

Note: For industrial temperature range product, add an "I" to the end of the part number.

### PACKAGE DIMENSIONS FOR JD1



\* ALL DIMENSIONS ARE IN MILLIMETERS AND (INCHES).

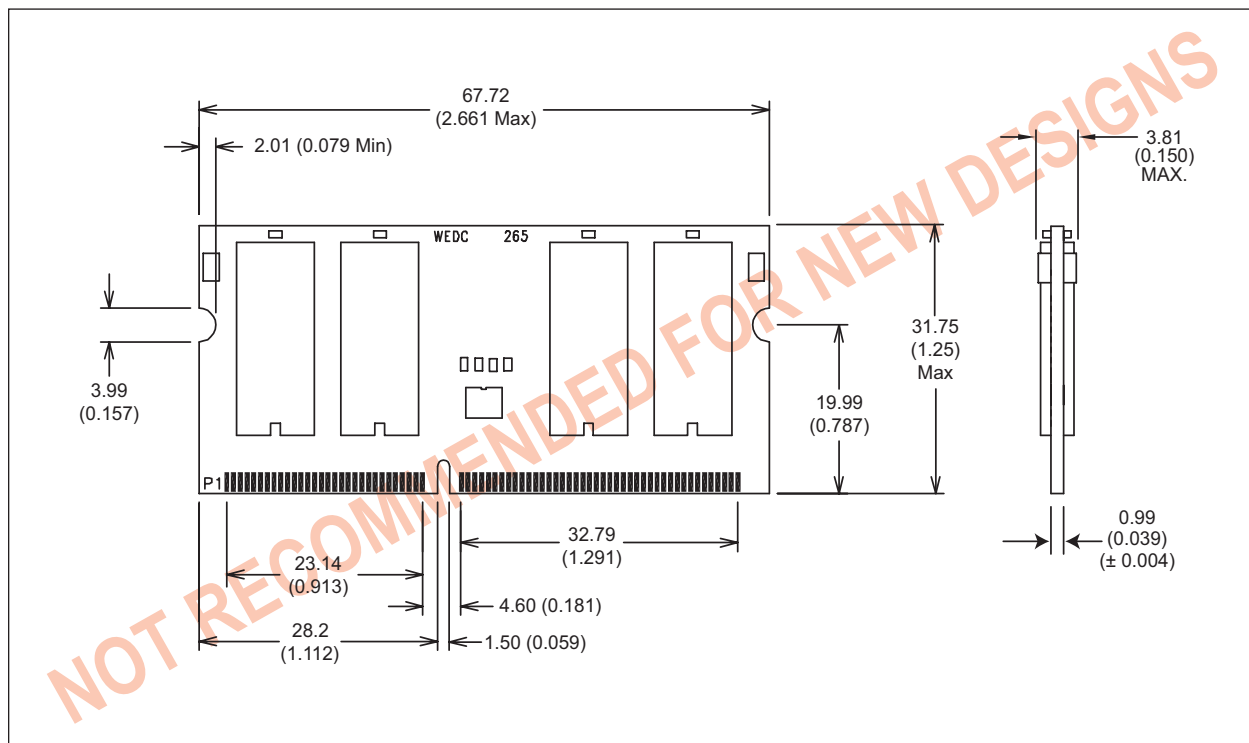


### PACKAGE DIMENSIONS FOR D1

| Ordering Information | Speed  | CAS Latency | Height*       |
|----------------------|--------|-------------|---------------|
| W3DG7216V10D1        | 100MHz | CL=2        | 31.75 (1.25") |
| W3DG7216V7D1         | 133MHz | CL=2        | 31.75 (1.25") |
| W3DG7216V75D1        | 133MHz | CL=3        | 31.75 (1.25") |

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### PACKAGE DIMENSIONS FOR D1



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### Document Title

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### Revision History

| Rev # | History                                                                                                                                                                         | Release Date | Status      |
|-------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|-------------|
| Rev 0 | History Paget                                                                                                                                                                   | 10-25-01     | Advanced    |
| Rev 1 | 1.1 Corrected mechanical drawing<br>1.2 Changed logo                                                                                                                            | 7-9-02       | Advanced    |
| Rev 2 | 2.1 Updated Datasheet (CAP and IDD spec)<br>2.2 Moved from Advanced to Preliminary<br>2.3 Added JD1 package option<br>2.4 "D1" package option "Not Recommended for New Designs" | 6-04         | Preliminary |